NSN 5962-01-154-7970

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View Online at https://aerobasegroup.com/nsn/5962-01-154-7970

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inche	s and 0.310 inches
Body Height:	
Between 0.140 inche	s and 0.185 inches
Maximum Power Dis	sipation Rating:
739.0 milliwatts	
Operating Tempuration	ure Range:
-55.0/+125.0 degrees	celsius
Storage Tempuratur	e Range:
-65.0/+150.0 degrees	celsius
Features Provided:	
Hermetically sealed a	nd monolithic and positive outputs and schottky and programmable and programmed and bipolar and w/enable and
w/decoded output and	d w/buffered output
Inclosure Material:	
Ceramic and glass	
Inclosure Configura	tion:
Dual-in-line	
Output Logic Form:	
Transistor-transistor I	ogic
Input Circuit Patterr	
10 input	
Case Outline Source	e And Designator:
D-2 mil-m-38510	
Terminal Surface Tr	eatment:
Solder	
Voltage Rating And	Type Per Characteristic:
5.5 volts power sour	ce
Time Rating Per Cha	acteristic:
75.00 nanoseconds	propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Typ	e:
Rom	
Memory Capacity:	
Unknown	
Test Data Documen	t:
81349-mil-m-38510 s	pecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes con	nmercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and pe	erformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	Quantity

Terminal Type And Quantity:

16 printed circuit

Shalf Life

Specification Data:

81349-mil-m-38510/203 government specification

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

